

Data sheet acquired from Harris Semiconductor

CMOS Dual 64-Stage Static Shift Register

High-Voltage Types (20-Volt Rating)

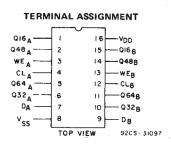
■ CD4517B dual 64-stage static shift register consists of two independent registers each having a clock, data, and write enable input and outputs accessible at taps following the 16th, 32nd, 48th, and 64th stages. These taps also serve as input points allowing data to be inputted at the 17th, 33rd, and 49th stages when the write enable input is a logic 1 and the clock goes through a low-to-high transition. The truth table indicates how the clock and write enable inputs control the operation of the CD4517B. Inputs at the intermediate taps allow entry of 64 bits into the register with 16 clock pulses. The 3-state outputs permit connection of this device to an external bus.

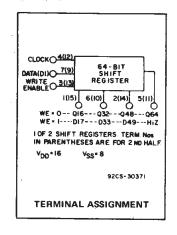
The CD4517B is supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Low quiescent current 10 nA/pkg (typ.)
 at V_{DD} = 5 V
- Clock frequency 12 MHz (typ.) at
 V_{DD} = 10 V
- Schmitt trigger clock inputs allow operation with very slow clock rise and fall times
- Capable of driving two low-power TTL loads, one low- power Schottky TTL load, or two HTL loads
- Three-state outputs
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

CD4517B Types





MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	
INPUT VOLTAGE RANGE, ALL INPUTS	
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C	. Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Ty	pes)
OPERATING-TEMPERATURE RANGE (TA)	
STORAGE TEMPERATURE RANGE (Tstg)	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max	+265°C

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIM	414417.0	
CHARACTERISTIC	MIN. MAX.		UNITS
Supply-Voltage Range (For T _A = Full Package Temperature Range)	3	18	v

Applications:

- Time-delay circuits
- Scratch-pad memories
- General-purpose serial shift-register applications

TRUTH TABLE

Clock	Write Enable	Data	Stage 16 Tap	Stage 32 Tap	Stage 48 Tap	Stage 64 Tap
0	0	Х	Q16	Q32	Q48	Q64
0	1	×	Z	Z.	z	z
1	0	×	Q16	Q32	Q48	Q64
1	1	×	Z	Z.	Z	z
	0	Diin	Q16	Q32	Q48	Q64
	1	DI In	D17 In	D33 In	D49 In	z
	0	x	Q16	Q32	Q48	Ω64
	1	X	Z	z	z	z

X = Don't Care

Z = High Impedance

92CM - 3109BRI

92CL - 32765

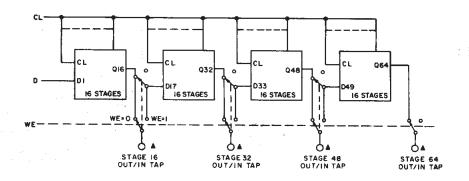
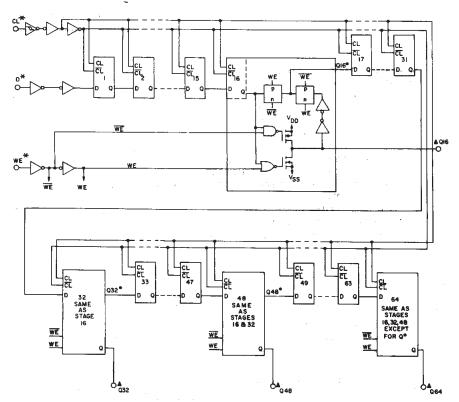


Fig. 1—CD4517B functional block diagram (one half).



VSS PROTECTED BY CMOS PROTECTION NETWORK

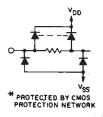


Fig. 2—CD4517B logic block diagram (one half).

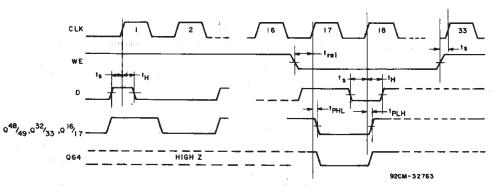


Fig. 3—Dynamic test waveforms.

CD4517B Types

CHARAC- TERISTIC	CON	DITIO	NS	LIN	LIMITS AT INDICATED TEMPERATURES (°C)						
	V _O (V)	V _{IN}	V _{DD}		–40	+85	+125	Min.	+25 Typ.	Max.	S
	 	0.5	5	5	5	150	150	-	0.04	5	┝
Quiescent Device		0,10	10	10	10	300	300		0.04	10	ł
Current,	_	0,15	15	20	20	600	600		0.04	20	μ
IDD Max.	_	0,20	20	100	100	3000	3000		0.08	100	
	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	-
Output Low (Sink) Current		0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	١.
OL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	
A	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	m
Output High (Source) Current, IOH Min.	2.5	0,5	5	-2	-1.8	-1.3		-1.6		_	
	9.5	0,10	10	1.6	-1.5	-1.1	-0.9	-1.3	→2.6		
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage:	_	0,5	5	0.05 – 0							┢
Low-Level,		0,10	10		0.	.05		0	0.05	1	
VOL Max.	-	0,15	15		0.	.05	_	0	0.05	١,	
Output	_	0,5	5	4.95					5	_	[
Voltage: High-Level,	-	0,10	10		9	95	9.95	10	_	1	
VOH Min.	_	0,15	15		14.	95	14.95	: 15	_	1	
	0.5,4.5		5			1.5				1.5	\vdash
Input Low Voltage	1,9	_	10			3			_	3	:
V _{IL} Max.	1.5,13.5	-	15		4					4	١,
Input High	0.5,4.5	_	5	3.5				3.5	_	_	1
Voltage,	1,9	_	10	,		7	7		_		
V _{IH} Min.	1.5,13:5	1	15			11:	11	_			
Input Current I _{IN} Max.	-	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μ
3-State Output Leakage Current IOUT Max.	0,18	0,18	18	±0.4	±0.4	±12	±12	-	±10 ⁻⁴	±0.4	μ

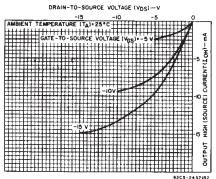


Fig. 7—Minimum p-channel output high (source) current characteristics.

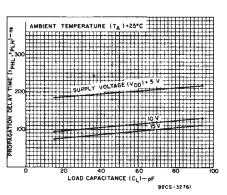


Fig. 8—Typical propagation delay time as a function of load capacitance.

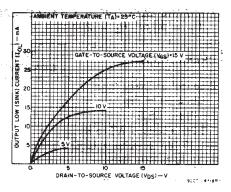


Fig. 4—Typical n-channel output low (sink) current characteristics.

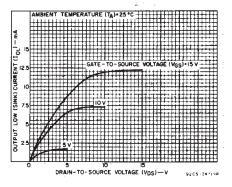


Fig. 5—Minimum n-channel output low (sink) current characteristics.

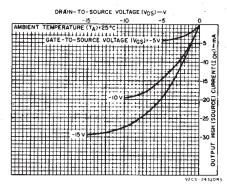


Fig. 6—Typical p-channel output high (source) current characteristics.

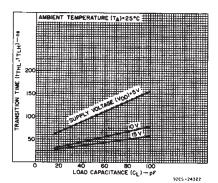


Fig. 9—Typical transition time a a function of load capacitance.

CD4517B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25\,^{\circ}C$; Input t_f , $t_f=20\,\rm ns$, $C_L=50\,\rm pF$, $R_L=200\,\rm k\Omega$

CHARACTERISTIC	TEST	14 00				
CHARACTERISTIC	CONDITIONS	V _{DD} (V)	Min.	LIMITS Typ.	Max.	UNITS
Propagation Delay Time:		5	_	200	400	-
CL to Bit 16 Tap		10		110	220	ns
tpHL, tpLH		15	_	90	180	
3-State Output, WE to Bit		5	_	75	150	
16 Tap tpHZ, tpLZ; tpZH,		. 10	- '	40	80	. ns
t _{PZL} (See Note)		15	_	30	60	
Output Transition Time		5	-	100	200	
tthu ttuh		10		50	100	ns
THE TER		15	_	40	80	
Write Enable-to-Clock		5 -	0	-50	-	
Setup Time		10	0	-25	_	ns
		15	0	-15		
Data-to-Clock		5	20	0	_	
Setup Time, ts		10	10	0	-	ns
		15	10	. 0		
Minimum Write		5	_	50	100	
Enable-to-Clock		10		25	50	ns
Release Time		15	_	20	40	
Minimum		-5	_	100	200	
Data-to-Clock		10	<u> </u>	50	100	ns
Hold Time, tH		15	_	25	50	
Minimum Clock Pulse		5	_	90	180	
Width, tw		10		40	80	ns
		15		25	50	
Maximum Clock Input		5	3	6	_	
Frequency, f _{CL}		10	6	12		MHz
, roducinoy, ICL		15	8	15		
Maximum Clock Input Rise		5				
or Fall Time, t _{fCL} t _{rCL}		10	UNLIMITED			μ\$
		15.				
Input Capacitance CIN	Any Inp	ut	_ 5 7.5 			pF

NOTE: Measured at the point of 10% change in output with an output load of 50 pF, RL = 1 k Ω to VDD for tpZL, tpLZ and RL = 1 k Ω to VSS for tpZH, tpHZ.

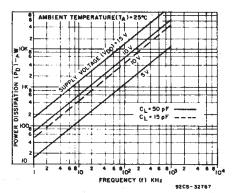
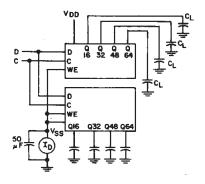


Fig. 10—Typical power dissipation as a function of frequency.



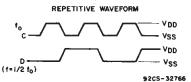


Fig. 11—Dynamic power dissipation test circuit and waveforms.

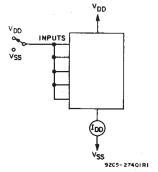


Fig. 12—Quiescent-device-current test circuit.

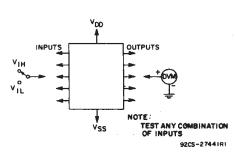


Fig. 13-Input-voltage test circuit.

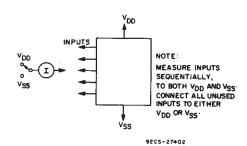
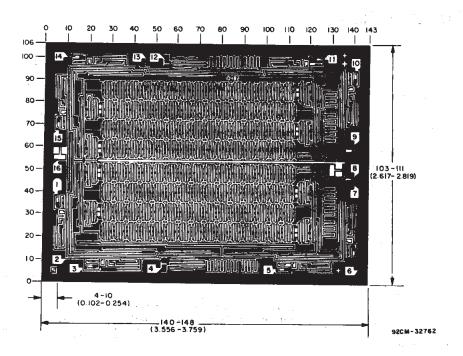


Fig. 14-input current test circuit.



Dimensions and pad layout for CD4517B.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils $(10^{\circ3} \text{ inch})$.

PACKAGE OPTION ADDENDUM

www.ti.com 15-Oct-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Pa	ackage Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4517BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4517BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4517BF3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

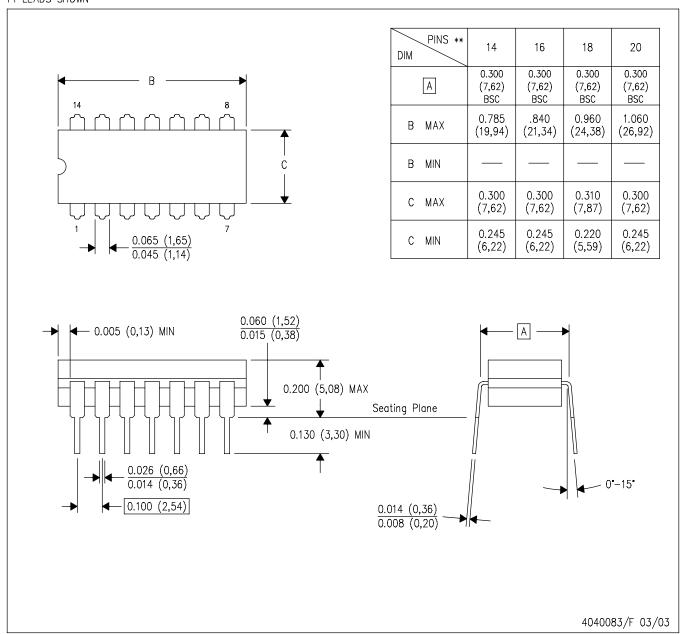
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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14 LEADS SHOWN



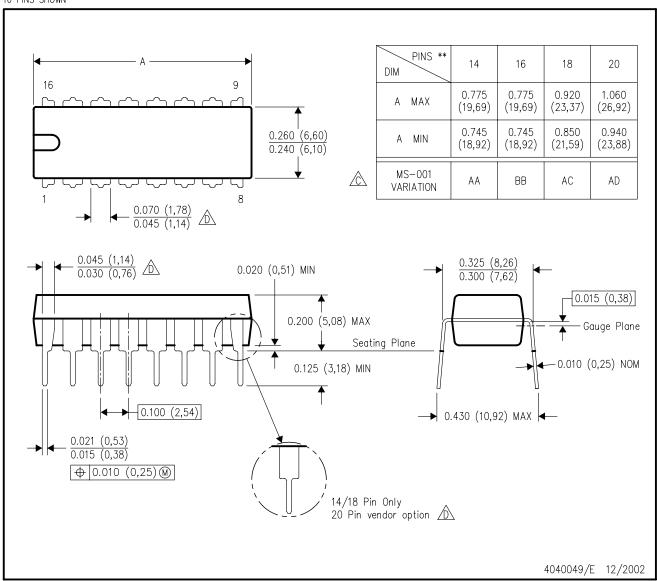
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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